AUTOMOTIVE GRADE

AUIRG4PC40S-E

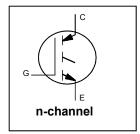
Insulated Gate Bipolar Transistor

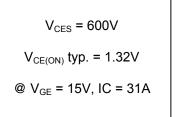
Features

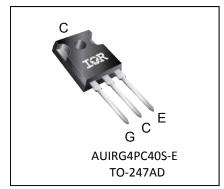
- Standard: Optimized for minimum saturation voltage and low operating frequencies (< 1kHz)
- Generation 4 IGBT design provides tighter parameter distribution and higher efficiency than Generation 3
- Industry standard TO-247AD package
- Lead-Free
- Automotive Qualified*

Benefits

- Generation 4 IGBT's offer highest efficiency available
- IGBT's optimized for specified application conditions
- Designed to be a "drop-in" replacement for equivalent industry-standard Generation 3 IR IGBT's







G	С	E
Gate	Collector	Emitter

Base part number	Package Type	Standard Pack		Orderable Part Number
		Form	Quantity	
AUIRG4PC40S-E	TO-247AD	Tube	25	AUIRG4PC40S-E

Absolute Maximum Ratings

	Parameter	Max.	Units V	
V _{CES}	Collector-to-Emitter Voltage	600		
I _C @ T _C = 25°C	Continuous Collector Current	60		
I _C @ T _C = 100°C	Continuous Collector Current	31	^	
I _{CM}	Pulse Collector Current ①	120	Α	
I _{LM}	Clamped Inductive Load Current ②	120		
$V_{\sf GE}$	Continuous Gate-to-Emitter Voltage	±20	V	
E _{ARV} Reverse Voltage Avalanche Energy ③		15		
P_D @ T_C = 25°C	Maximum Power Dissipation	160	W	
P _D @ T _C = 100°C Maximum Power Dissipation		65	VV	
TJ	Operating Junction and	-55 to +150		
T_{STG}	Storage Temperature Range			
	Soldering Temperature, for 10 sec.	300 (0.063 in. (1.6mm) from case)	С	
	Mounting Torque, 6-32 or M3 Screw	10 lbf·in (1.1 N·m)		

Thermal Resistance

	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Thermal Resistance Junction-to-Case		0.77	
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink (flat, greased surface)	0.24		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient (typical socket mount)		40	
Wt	Weight	6 (0.21)		g (oz)

^{*} Qualification standard can be found at http://www.irf.com/



Electrical Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max.	Units	Conditions
$V_{(BR)CES}$	Collector-to-Emitter Breakdown Voltage	600	_	_		$V_{GE} = 0V, I_{C} = 250\mu A$
$V_{(BR)ECS}$	Emitter-to-Collector Breakdown Voltage @	18	_		V	$V_{GE} = 0V, I_{C} = 1.0A$
$\Delta V_{(BR)CES}/\Delta T_J$	Temperature Coeff. of Breakdown Voltage	_	0.75	_	V/°C	$V_{GE} = 0V, I_C = 1mA$
		1	1.32	1.5		$I_{C} = 31A, V_{GE} = 15V, T_{J} = 25^{\circ}C$
$V_{CE(on)}$	Collector-to-Emitter Saturation Voltage	1	1.68		V	I_C = 60A, V_{GE} = 15V, See Fig. 2,5
			1.32			$I_C = 31A$, $V_{GE} = 15V$, $T_J = 150$ °C
$V_{GE(th)}$	Gate Threshold Voltage	3.0	_	6.0	V	$V_{CE} = V_{GE}$, $I_C = 250\mu A$
$\Delta V_{GE(th)}/\Delta T_{J}$	Threshold Voltage Temperature Coeff.	_	-9.3	_	mV/°C	$V_{CE} = V_{GE}$, $I_C = 250\mu A$
gfe	Forward Transconductance®	12	21		S	$V_{CE} = 100V, I_{C} = 31A$
				250		$V_{GE} = 0V, V_{CE} = 600V$
I _{CES}	Collector-to-Emitter Leakage Current	-		2.0	μΑ	$V_{GE} = 0V, V_{CE} = 10V, T_{J} = 25^{\circ}C$
				1000		$V_{GE} = 0V, V_{CE} = 600V, T_{J} = 150^{\circ}C$
I_{GES}	Gate-to-Emitter Leakage Current	_		±100	nA	$V_{GE} = \pm 20V$

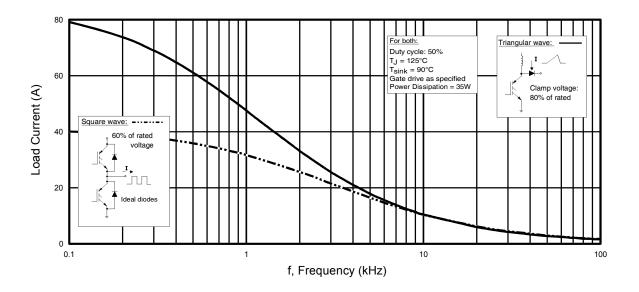
Switching Characteristics @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Тур.	Max	Units	Conditions	
Q_q	Total Gate Charge (turn-on)	_	100	150		I _C = 31A	
Q_{ge}	Gate-to-Emitter Charge (turn-on)	_	14	21	nC	V _{GE} = 15V See Fig.8	
Q_{gc}	Gate-to-Collector Charge (turn-on)	_	34	51		V _{CC} = 400V	
$t_{d(on)}$	Turn-On delay time	_	22				
t _r	Rise time	_	18		no	$I_C = 31A$, $V_{CC} = 480V$, $V_{GE} = 15V$	
$t_{d(off)}$	Turn-Off delay time	_	650	980	ns	$R_G = 10\Omega, T_J = 25^{\circ}C$	
t _f	Fall time		380	570			
Eon	Turn-On Switching Loss	_	0.45	_		Energy losses include "tail"	
E _{off}	Turn-Off Switching Loss	_	6.5	_	mJ	See Fig. 10, 11, 13, 14	
E_ts	Total Switching Loss	_	6.95	9.9			
$t_{d(on)}$	Turn-On delay time	_	23	_		$I_C = 31A$, $V_{CC} = 480V$, $V_{GE} = 15V$	
t _r	Rise time	_	21	_]	$R_G = 10\Omega, T_J = 150^{\circ}C$	
$t_{d(off)}$	Turn-Off delay time	_	1000		ns	Energy losses include "tail"	
t _f	Fall time	_	940	_	1	Lifergy losses include tall	
E _{ts}	Total Switching Loss	_	12		mJ	See Fig. 13, 14	
L _E	Internal Emitter Inductance	_	13		nH	Measured 5mm from package	
C _{ies}	Input Capacitance	_	2200			V _{GE} = 0V	
C _{oes}	Output Capacitance		140		pF	$V_{CC} = 30V$ See Fig. 7	
C _{res}	Reverse Transfer Capacitance	_	26			f = 1.0Mhz	

Notes

- \odot Repetitive rating; V_{GE} = 20V, pulse width limited by max. junction temperature. (See fig. 13b)
- ③ Repetitive rating; pulse width limited by maximum junction temperature.
- ④ Pulse width $\leq 80\mu s$; duty factor $\leq 0.1\%$.
- S Pulse width 5.0µs, single shot.





 $\label{eq:Fig.1} \textbf{Fig. 1} - \text{Typical Load Current vs. Frequency} \\ \text{(For square wave, } I=I_{\text{RMS}} \text{ of fundamental; for triangular wave, } I=I_{\text{PK}}) \\$

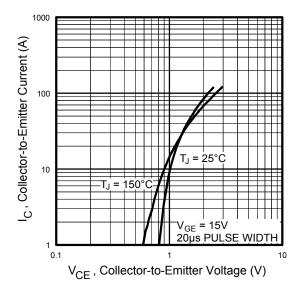


Fig. 2 - Typical Output Characteristics

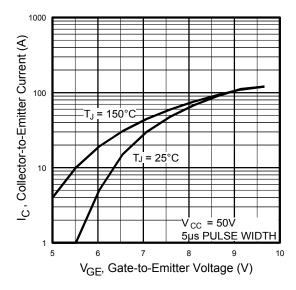


Fig. 3 - Typical Transfer Characteristics



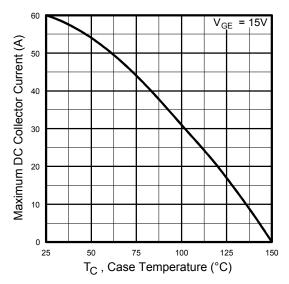


Fig. 4 - Maximum Collector Current vs. Case Temperature

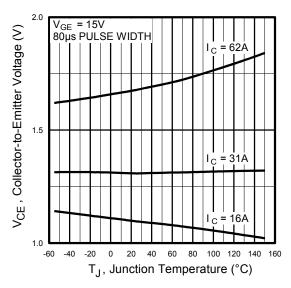


Fig. 5 - Collector-to-Emitter Voltage vs. Junction Temperature

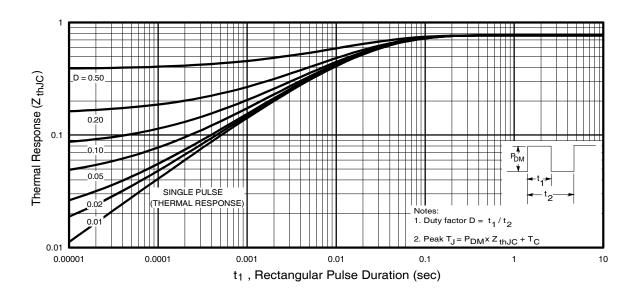


Fig. 6 - Maximum Effective Transient Thermal Impedance, Junction-to-Case



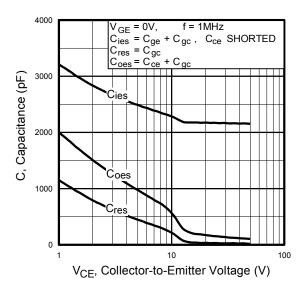


Fig. 7 - Typical Capacitance vs. Collector-to-Emitter Voltage

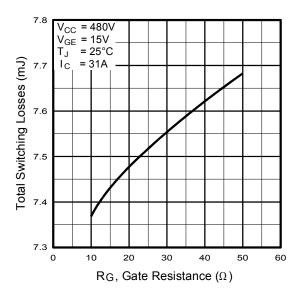


Fig. 9 - Typical Switching Losses vs. Gate Resistance

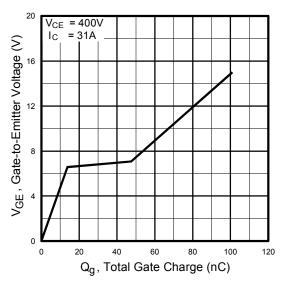


Fig. 8 - Typical Gate Charge vs. Gate-to-Emitter Voltage

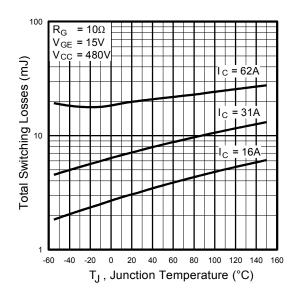


Fig. 10 - Typical Switching Losses vs. Junction Temperature



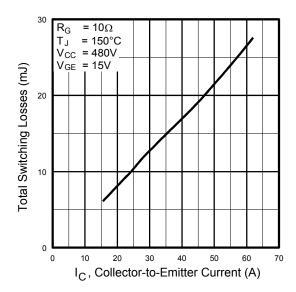


Fig. 11 - Typical Switching Losses vs. Collector-to-Emitter Current

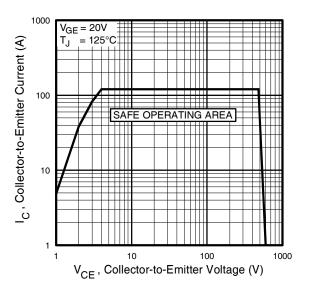


Fig. 12 - Turn-Off SOA



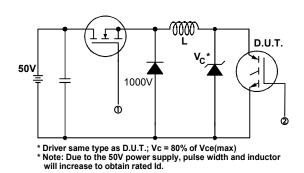


Fig. 13a - Clamped Inductive Load Test Circuit

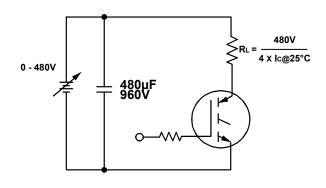
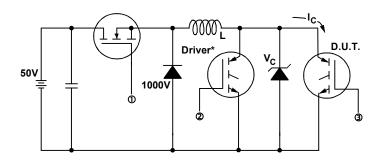


Fig. 13b - Pulsed Collector Current Test Circuit



* Driver same type as D.U.T., VC = 480V

Fig. 14a - Switching Loss Test Circuit

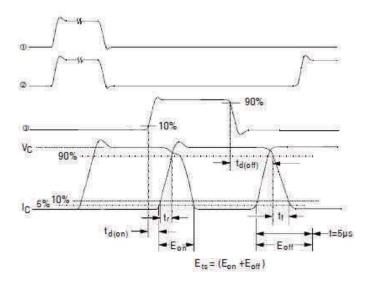
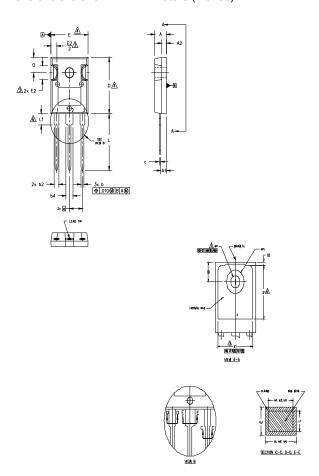


Fig. 14b - Switching Loss Waveforms



TO-247AD Package Outline

Dimensions are shown in millimeters (inches)



NOTES:

- DIMENSIONING AND TOLERANGING AS PER ASME Y14.5M 1994.
- DIMENSIONS ARE SHOWN IN INCHES.

CONTOUR OF SLOT OPTIONAL.

DIMENSION D & E DO NOT INCLUDE MOLD FLASH. WOLD FLASH SHALL NOT EXCEED .005" (0.127) PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE DUTERMOST EXTREMES OF THE PLASTIC BODY.

THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS DI & E1.

LEAD FINISH UNCONTROLLED IN L1.

OF TO HAVE A MAXIMUM DRAFT ANGLE OF 1.5 1 TO THE TOP OF THE PART WITH A MAXIMUM HOLE DIAMETER OF .154 INCH.

DUTLINE CONFORMS TO JEDEC OUTLINE TO-247AD.

SYMBOL	INCHES		MILLIM	MILLIME TERS		
	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	.183	.209	4.65	5.31		
A1	.D87	.102	2.21	2.59		
A2	.059	.098	1.50	2.49		
ь	.D.39	.055	0.99	1.40		
b1	.039	.053	0.99	1,35		
b2	.D65	.094	1.65	2.39		
b3	.D65	.092	1.65	2.34		
ь4	.102	.135	2.59	3.43		
b5	.1D2	.133	2.59	3.3B		
С	.015	.035	0.38	0.89		
c1	.015	.O33	D.38	0.84		
D	.776	.815	19.71	20.70	4	
D1	.515	-	13.08	-	5	
D2	.D2D	.d53	D.51	1.35		
E	,602	.625	15.29	15.87	4	
E1	.5JD	-	13.46	-		
E2	.178	.216	4.52	5.49		
е	.215	BSC	5.46	5.46 BSC		
øk	.0	10	٥.	25	1	
L	.78D	.827	19.57	21.00		
L1	.146	.169	3.71	4.29		
øP	.140	.144	3,56	3.66		
Ø₽1	-	.291	-	7.39		
Q	.209 .224		5,31	5.69		
S	.217	BSC	5.51	BSC]	
1					I	

LEAD ASSIGNMENTS

HEXFET

- 1.- GATE
- 2.- DRAIN 3.- SOURCE
- 4.- DRAIN

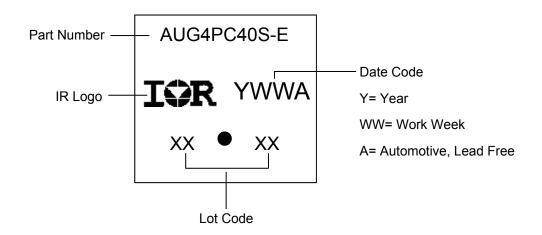
IGBTs, CaPACK

- 1.- GATE 2.- COLLECTOR
- 3.- EMITTER
- 4.- COLLECTOR

<u>DIODES</u>

- 1.- ANODE/OPEN
- Z.- CATHODE
- 3.- ANODE

TO-247AD Part Marking Information



TO-247AD package is not recommended for Surface Mount Application.

Note: For the most current drawing please refer to IR website at http://www.irf.com/package/



Qualification Information[†]

		Automotive (per AEC-Q101) ††					
		Comments: This part number(s) passed Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.					
Moisture Sensitivity Level		TO-247AD N/A					
	Human Body Model	Class H1C (+/- 2000V)					
		AEC-Q101-001					
ESD		Class C5 (+/- 2000V)					
Charged Device Mod		AEC-Q101-005					
RoHS Compliant		Yes					

- † Qualification standards can be found at International Rectifier's web site: http://www.irf.com/
- †† Exceptions to AEC-Q101 requirements are noted in the qualification report.



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http://www.irf.com/technical-info/

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